


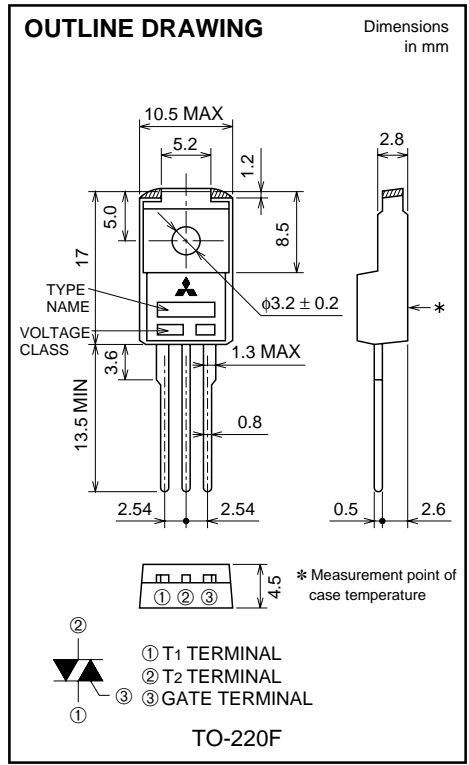
BCR12PM-14

MEDIUM POWER USE
INSULATED TYPE, PLANAR PASSIVATION TYPE

BCR12PM-14



- IT (RMS) 12A
- VDRM 700V
- IFGT I , IRGT I , IRGT III 30mA
- V_{iso} 2000V
- UL Recognized: Yellow Card No.E80276(N)
File No. E80271



APPLICATION

Switching mode power supply, light dimmer, electric flasher unit, hair driver, control of household equipment such as TV sets · stereo · refrigerator · washing machine · infrared kotatsu · carpet, solenoid drivers, small motor control, copying machine, electric tool

MAXIMUM RATINGS

Symbol	Parameter	Voltage class	
		14	Unit
VDRM	Repetitive peak off-state voltage *1	700	V
VDSM	Non-repetitive peak off-state voltage *1	840	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, T _c =74°C	12	A
ITSM	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	120	A
I ² _t	I ² _t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
P _{GM}	Peak gate power dissipation		5	W
P _{G (AV)}	Average gate power dissipation		0.5	W
V _{GM}	Peak gate voltage		10	V
I _{GM}	Peak gate current		2	A
T _j	Junction temperature		-40 ~ +125	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.0	g
V _{iso}	Isolation voltage	T _a =25°C, AC 1 minute, T1 · T2 · G terminal to case	2000	V

*1. Gate open.

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ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
IDRM	Repetitive peak off-state current	$T_j=125^{\circ}\text{C}$, V_{DRM} applied	—	—	2.0	mA	
VTM	On-state voltage	$T_c=25^{\circ}\text{C}$, $I_{\text{TM}}=20\text{A}$, Instantaneous measurement	—	—	1.6	V	
VFGT I	Gate trigger voltage *2	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $R_L=6\Omega$, $R_G=330\Omega$	I	—	—	1.5	V
VRGT I			II	—	—	1.5	V
VRGT III			III	—	—	1.5	V
IFGT I	Gate trigger current *2	$T_j=25^{\circ}\text{C}$, $V_D=6\text{V}$, $R_L=6\Omega$, $R_G=330\Omega$	I	—	—	30	mA
IRGT I			II	—	—	30	mA
IRGT III			III	—	—	30	mA
VGD	Gate non-trigger voltage	$T_j=125^{\circ}\text{C}$, $V_D=1/2V_{\text{DRM}}$	0.2	—	—	V	
Rth (j-c)	Thermal resistance	Junction to case *3	—	—	3.5	$^{\circ}\text{C}/\text{W}$	
$(dv/dt)_c$	Critical-rate of rise of off-state commutating voltage *4	$T_j=125^{\circ}\text{C}$	10	—	—	$\text{V}/\mu\text{s}$	

*2. Measurement using the gate trigger characteristics measurement circuit.

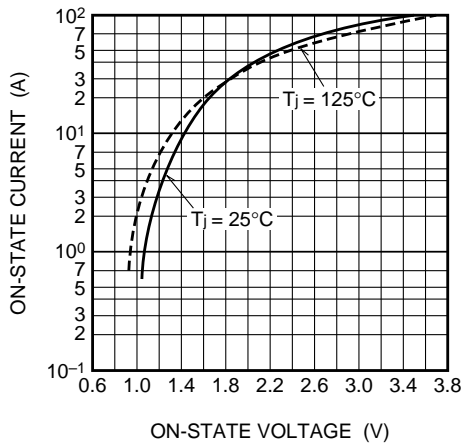
*3. The contact thermal resistance $R_{th(c-f)}$ in case of greasing is $0.5^{\circ}\text{C}/\text{W}$.

*4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

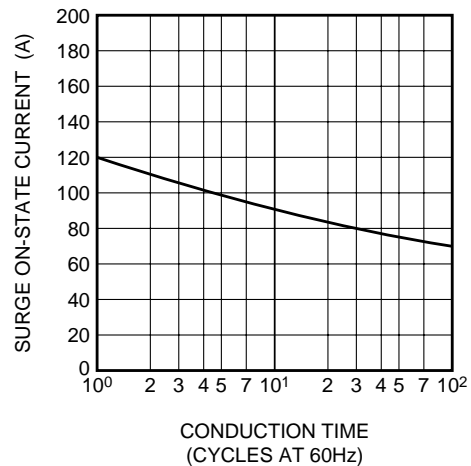
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature $T_j=125^{\circ}\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_c=-6.0\text{A}/\text{ms}$ 3. Peak off-state voltage $V_D=400\text{V}$	

PERFORMANCE CURVES

MAXIMUM ON-STATE CHARACTERISTICS



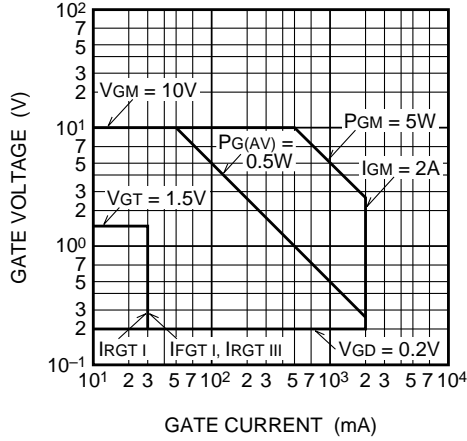
RATED SURGE ON-STATE CURRENT



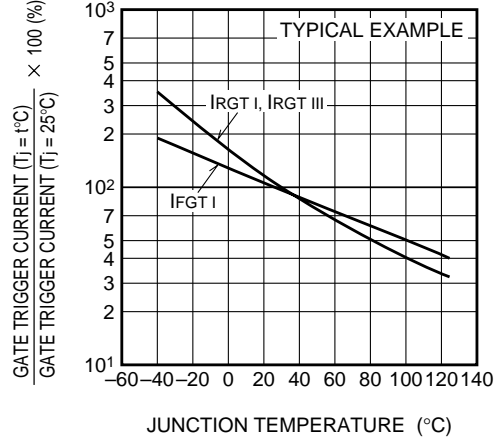
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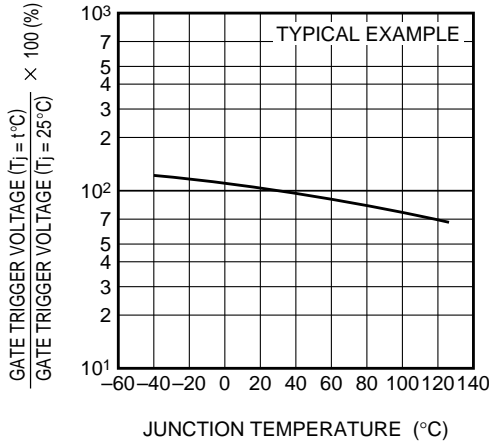
GATE CHARACTERISTICS



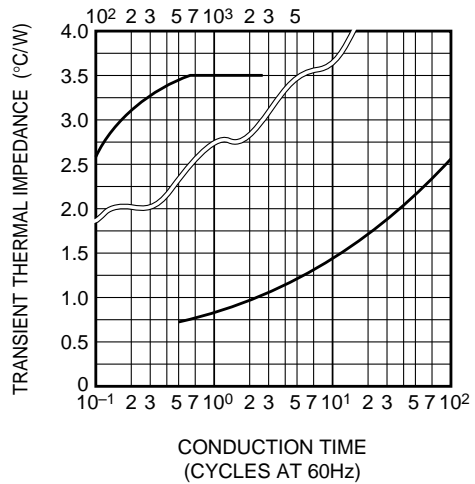
GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE



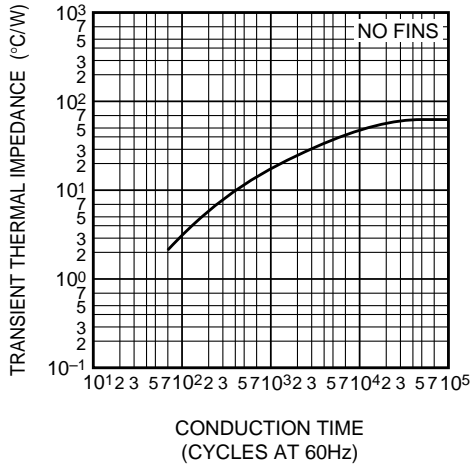
GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE



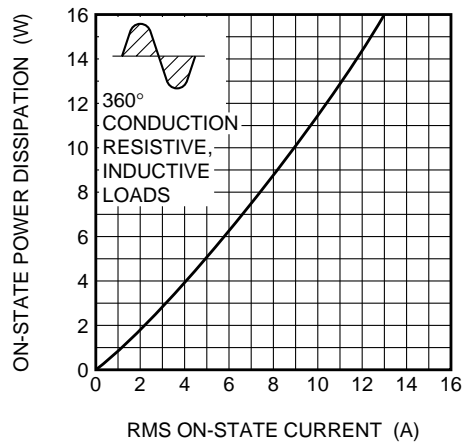
MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)



MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO AMBIENT)

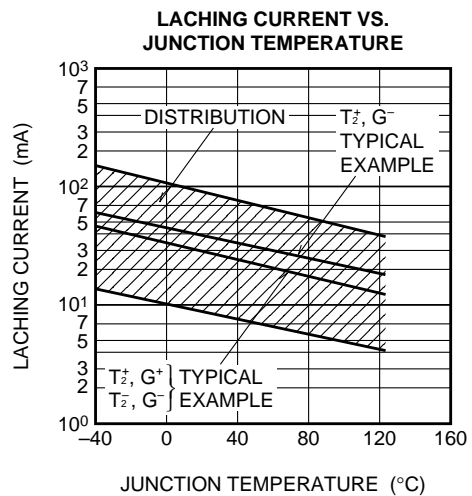
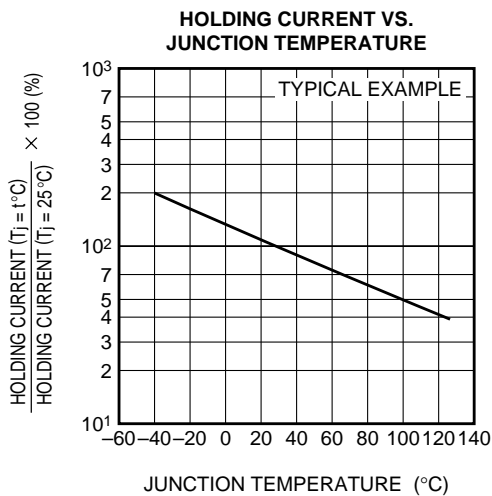
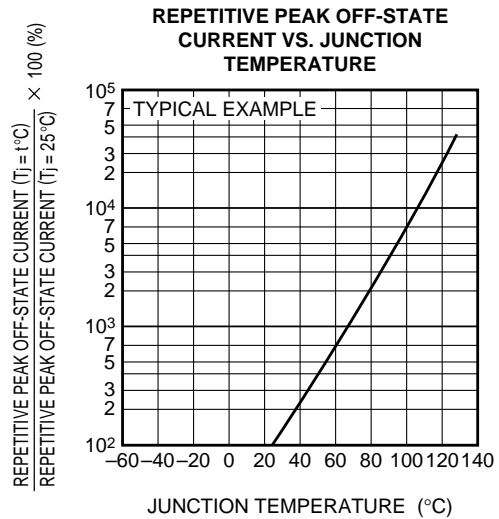
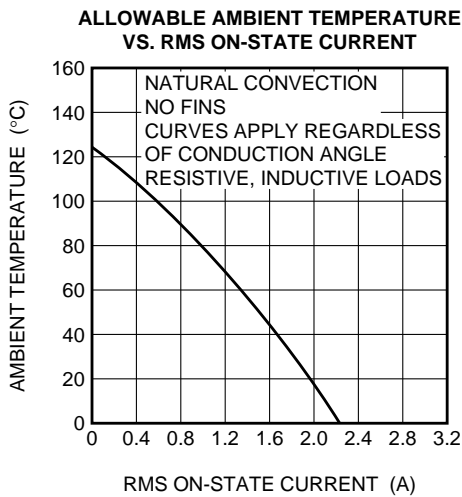
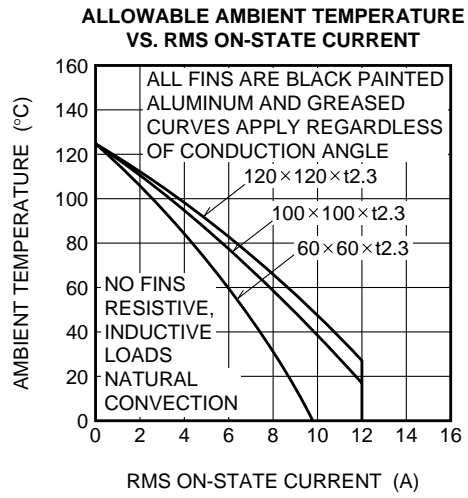
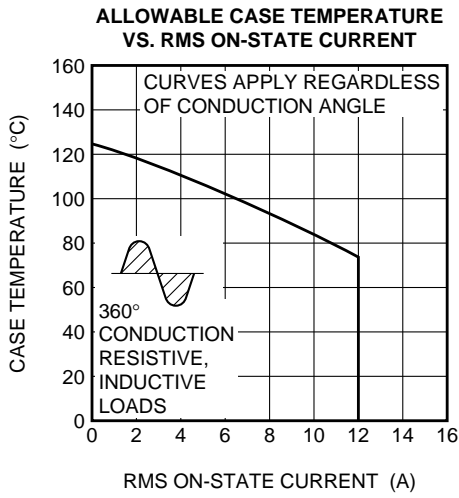


MAXIMUM ON-STATE POWER DISSIPATION



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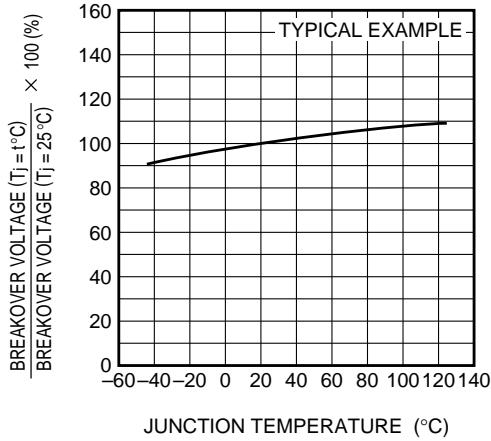
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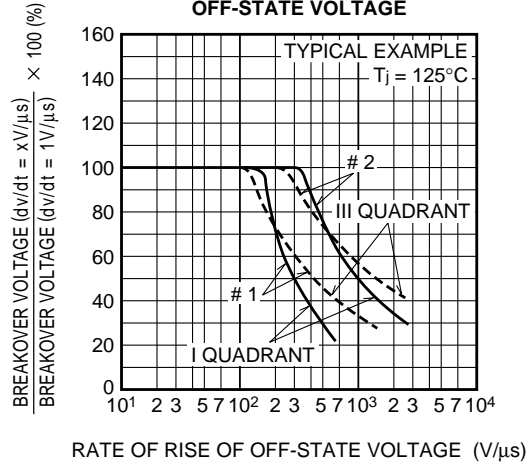
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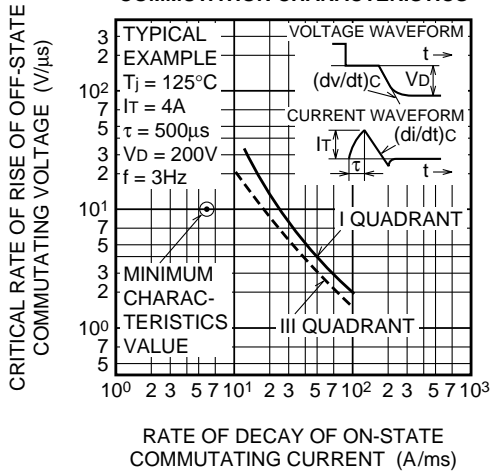
BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE



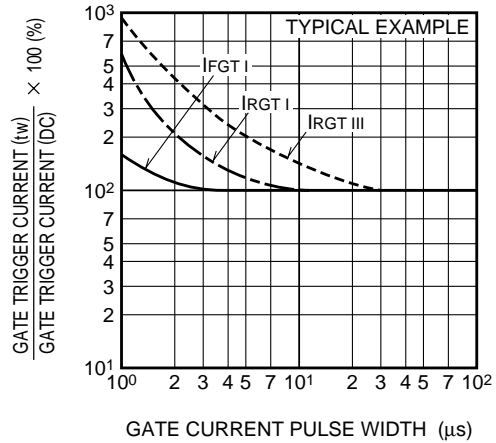
BREAKOVER VOLTAGE VS. RATE OF RISE OF OFF-STATE VOLTAGE



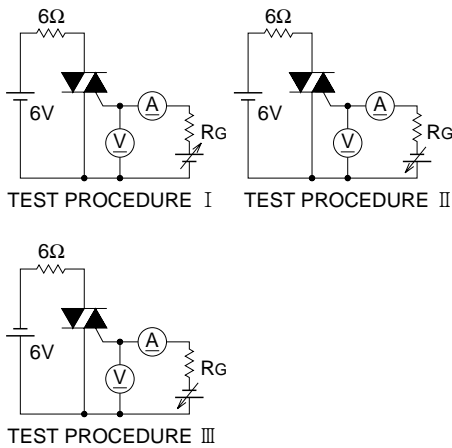
COMMUTATION CHARACTERISTICS



GATE TRIGGER CURRENT VS. GATE CURRENT PULSE WIDTH



GATE TRIGGER CHARACTERISTICS TEST CIRCUITS





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